Status Update

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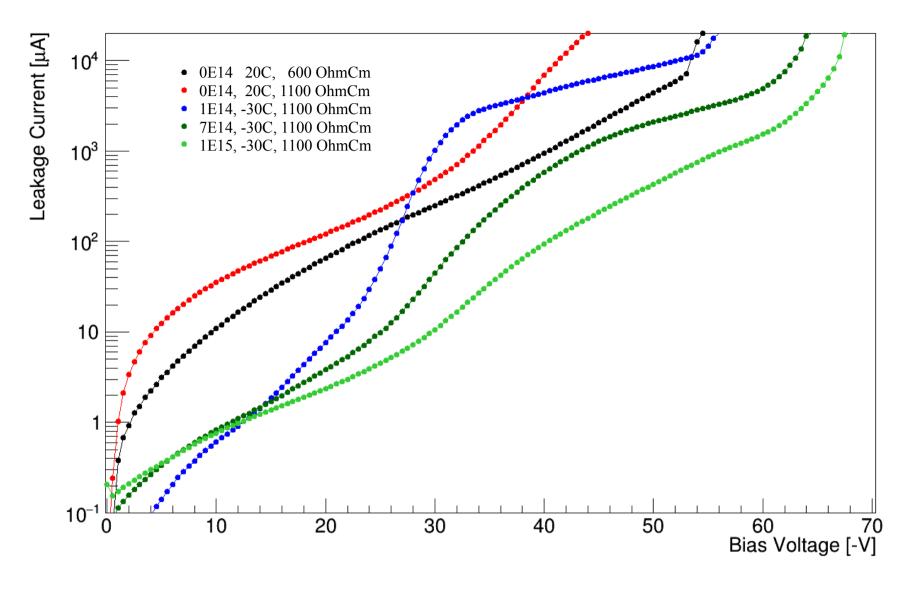




LF2 – Irradiated devices

- Sent 6 LF2 chips to JSI Ljubljana for neutron irradiation:
 - $-2x 1E14 n_{eq}/cm^2$
 - $-2x 7E14 n_{eq}/cm^2$
 - $-2x 1E15 n_{eq}/cm^2$
- Assembled one device of each fluence
- Performed same tests as for unirradiated devices, but at -30C

IVs for different irradiations

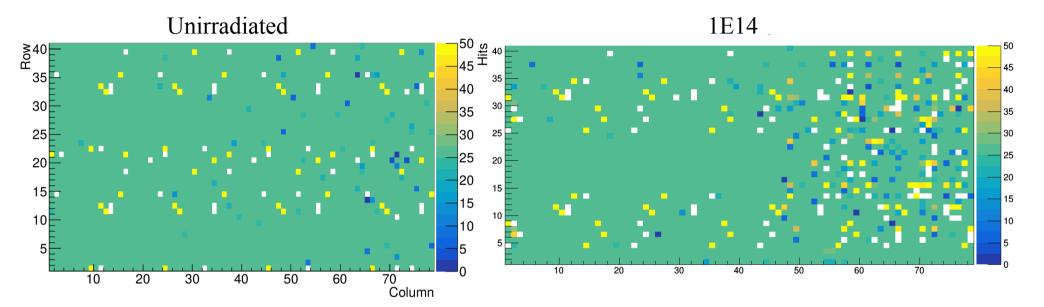


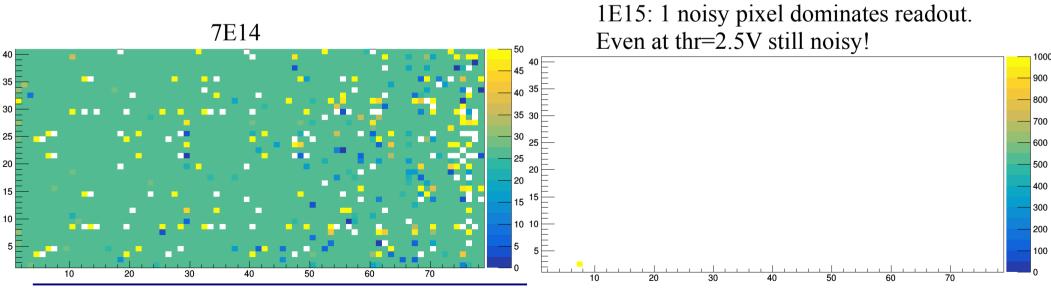
Note: higher irradiated devices seem to have better I-V behavior at -30C. Simulated breakdown voltage was at $\sim 80V \rightarrow \text{getting closer with irradiation!}$



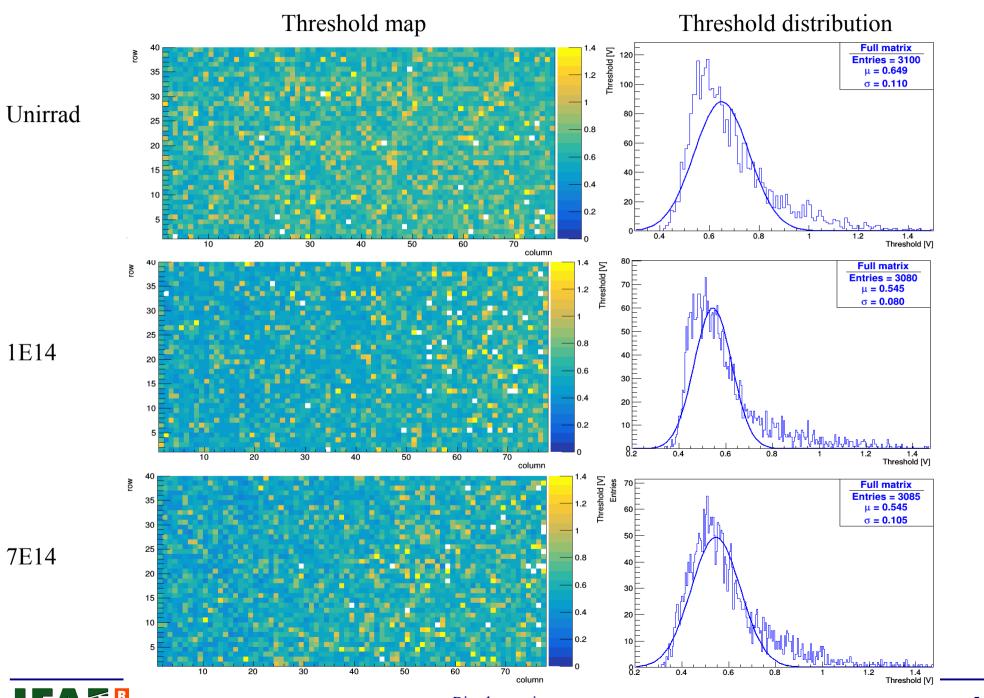
LF2 – Analog Scans

- Analog scans performed with the same setting for all devices
 - → No DAC tuning for each device done





LF2 – Threshold Scans





LF2 – Irradiated devices summary

- Irradiated 6 sensors and tested one of each fluence:
 - $-2x 1E14 n_{eq}/cm^2$
 - $-2x 7E14 n_{eq}/cm^2$
 - $-2x 1E15 n_{eq}/cm^2$
- IV behavior seems to improve
- All chips still configurable and responding
- Analog and threshold scan seem to give similar results, independent of irradiation
- 1E15 has a noisy pixel that makes readout impossible
 - → Will try to mount the other module to see if this helps
- TODO: Check if all devices see Sr90 source



Pixel meeting